

2-Input AND Gate with Open Drain Output

MC74VHC1G09

The MC74VHC1G09 is an advanced high speed CMOS 2-input AND gate with open drain output fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining CMOS low power dissipation.

The input structures provide protection when voltages up to 5.5 V are applied, regardless of the supply voltage. This allows the device to be used to interface 5 V circuits to 3 V circuits. Some output structures also provide protection when $V_{CC} = 0$ V and when the output voltage exceeds V_{CC} . These input and output structures help prevent device destruction caused by supply voltage – input/output voltage mismatch, battery backup, hot insertion, etc.

Features

- Designed for 2.0 V to 5.5 V V_{CC} Operation
- 4.3 ns t_{PD} at 5 V (typ)
- Inputs/Outputs Over-Voltage Tolerant up to 5.5 V
- I_{OFF} Supports Partial Power Down Protection
- Source/Sink 8 mA at 3.0 V
- Available in SC-88A and SC-74A Packages
- Chip Complexity < 100 FETs
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

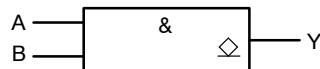
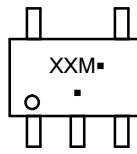


Figure 1. Logic Symbol

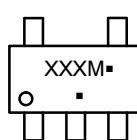
MARKING DIAGRAMS



SC-88A
DF SUFFIX
CASE 419A



SC-74A
DBV SUFFIX
CASE 318BQ



XX = Specific Device Code
M = Date Code*
- = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 6 of this data sheet.

MC74VHC1G09

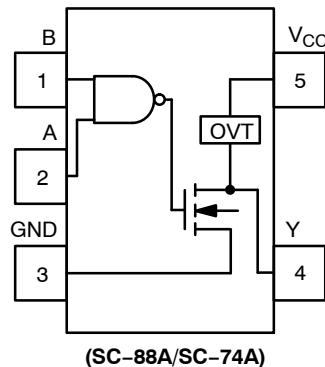


Figure 2. Pinout (Top View)

PIN ASSIGNMENT

Pin	Function
1	B
2	A
3	GND
4	Y
5	V _{CC}

FUNCTION TABLE

Input		Output
A	B	Y
L	L	L
L	H	L
H	L	L
H	H	Z

MAXIMUM RATINGS

Symbol	Characteristics	Value	Unit
V _{CC}	DC Supply Voltage	-0.5 to +6.5	V
V _{IN}	DC Input Voltage	-0.5 to +6.5	V
V _{OUT}	DC Output Voltage	Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V _{CC} = 0 V)	-0.5 to V _{CC} + 0.5 -0.5 to +6.5 -0.5 to +6.5
I _{IK}	DC Input Diode Current	V _{IN} < GND	-20
I _{OK}	DC Output Diode Current	V _{OUT} < GND	-20
I _{OUT}	DC Output Source/Sink Current		±25
I _{CC} or I _{GND}	DC Supply Current per Supply Pin or Ground Pin		±50
T _{STG}	Storage Temperature Range	-65 to +150	°C
T _L	Lead Temperature, 1 mm from Case for 10 secs	260	°C
T _J	Junction Temperature Under Bias	+150	°C
θ _{JA}	Thermal Resistance (Note 2)	SC-88A SC-74A	377 320
P _D	Power Dissipation in Still Air	SC-88A SC-74A	332 390
MSL	Moisture Sensitivity	Level 1	-
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in
V _{ESD}	ESD Withstand Voltage (Note 3)	Human Body Model Charged Device Model	2000 1000
I _{Latchup}	Latchup Performance (Note 4)		± 100
			mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Applicable to devices with outputs that may be tri-stated.
2. Measured with minimum pad spacing on an FR4 board, using 10mm-by-1inch, 2 ounce copper trace no air flow per JESD51-7.
3. HBM tested to ANSI/ESDA/JEDEC JS-001-2017. CDM tested to EIA/JESD22-C101-F. JEDEC recommends that ESD qualification to EIA/JESD22-A115-A (Machine Model) be discontinued per JEDEC/JEP172A.
4. Tested to EIA/JESD78 Class II.

RECOMMENDED OPERATING CONDITIONS

Symbol	Characteristics	Min	Max	Unit	
V _{CC}	Positive DC Supply Voltage	2.0	5.5	V	
V _{IN}	DC Input Voltage	0	5.5	V	
V _{OUT}	DC Output Voltage	0 0 0	V _{CC} 5.5 5.5	V	
T _A	Operating Temperature Range	-55	+125	°C	
t _r , t _f	Input Rise and Fall Time	V _{CC} = 2.0 V V _{CC} = 2.3 V to 2.7 V V _{CC} = 3.0 V to 3.6 V V _{CC} = 4.5 V to 5.5 V	0 0 0 0	20 20 10 5	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.



DC ELECTRICAL CHARACTERISTICS (MC74VHC1G09)

Symbol	Parameter	Test Conditions	V _{CC} (V)	T _A = 25 °C			−40 °C ≤ T _A ≤ 85 °C		−55 °C ≤ T _A ≤ 125 °C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
V _{IH}	High-Level Input Voltage		2.0	1.5	—	—	1.5	—	1.5	—	V
			3.0	2.1	—	—	2.1	—	2.1	—	
			4.5	3.15	—	—	3.15	—	3.15	—	
			5.5	3.85	—	—	3.85	—	3.85	—	
V _{IL}	Low-Level Input Voltage		2.0	—	—	0.5	—	0.5	—	0.5	V
			3.0	—	—	0.9	—	0.9	—	0.9	
			4.5	—	—	1.35	—	1.35	—	1.35	
			5.5	—	—	1.65	—	1.65	—	1.65	
V _{OL}	Low-Level Output Voltage	V _{IN} = V _{IH} or V _{IL} I _{OL} = 50 µA I _{OL} = 50 µA I _{OL} = 50 µA I _{OL} = 4 mA I _{OL} = 8 mA	2.0	—	0.0	0.1	—	0.1	—	0.1	V
			3.0	—	0.0	0.1	—	0.1	—	0.1	
			4.5	—	0.0	0.1	—	0.1	—	0.1	
			3.0	—	—	0.36	—	0.44	—	0.52	
			4.5	—	—	0.36	—	0.44	—	0.52	
			2.0 to 5.5	—	—	±0.1	—	±1.0	—	±1.0	µA
I _{IN}	Input Leakage Current	V _{IN} = 5.5 V or GND	5.5	—	—	±0.25	—	±2.5	—	±2.5	µA
I _{OZ}	3-State Output Leakage Current	V _{OUT} = 0 V to 5.5 V	0.0	—	—	1.0	—	10	—	10	µA
I _{OFF}	Power Off Leakage Current	V _{IN} = 5.5 V or V _{OUT} = 5.5 V	5.5	—	—	1.0	—	20	—	40	µA

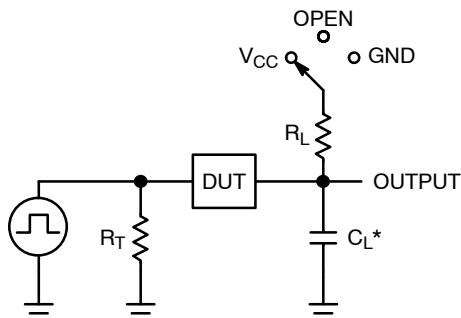
AC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Conditions	V _{CC} (V)	T _A = 25 °C			−40 °C ≤ T _A ≤ 85 °C		−55 °C ≤ T _A ≤ 125 °C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
t _{PZL}	Propagation Delay, (A or B) to Y (Figures 3 and 4)	C _L = 15 pF	3.0 to 3.6	—	6.2	8.8	—	10.5	—	12.5	ns
				—	8.7	12.3	—	14.0	—	16.5	
		C _L = 50 pF	4.5 to 5.5	—	4.3	5.9	—	7.0	—	9.0	
				—	5.8	7.9	—	9.0	—	11.0	
t _{PLZ}	Propagation Delay, (A or B) to Y (Figures 3 and 4)	C _L = 15 pF	3.0 to 3.6	—	6.5	9.7	—	11.5	—	14.5	ns
				—	8.7	12.3	—	14.0	—	16.5	
		C _L = 50 pF	4.5 to 5.5	—	4.8	6.8	—	8.0	—	10.0	
				—	5.8	7.9	—	9.0	—	11.0	
C _{IN}	Input Capacitance			—	4.0	10	—	10	—	10	pF
C _{OUT}	Output Capacitance	Output in High Impedance State		—	6.0	—	—	—	—	—	pF
C _{PD}	Power Dissipation Capacitance (Note 5)							Typical @ 25 °C, V _{CC} = 5.0 V			pF
								8.0			

5. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no-load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.



MC74VHC1G09



C_L includes probe and jig capacitance

R_T is Z_{OUT} of pulse generator (typically 50 Ω)

$f = 1$ MHz

Figure 3. Test Circuit

Test	Switch Position	C_L , pF	R_L , Ω
t_{PLH} / t_{PHL}	Open	See AC Characteristics Table	X
t_{PLZ} / t_{PZL}	V_{CC}		1 k
t_{PHZ} / t_{PZH}	GND		1 k

X = Don't Care

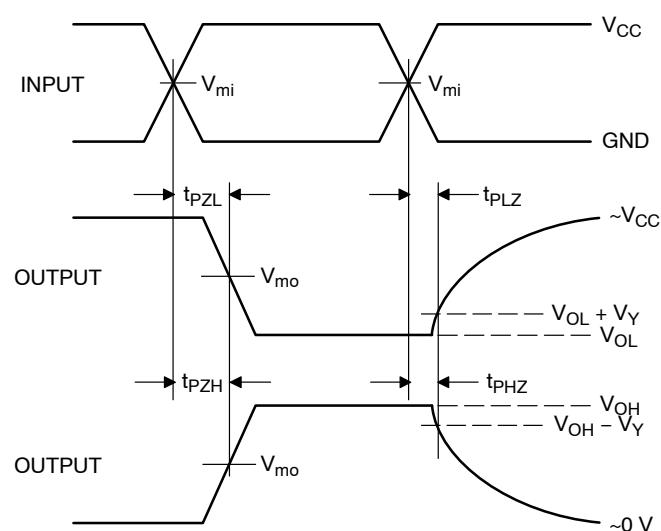
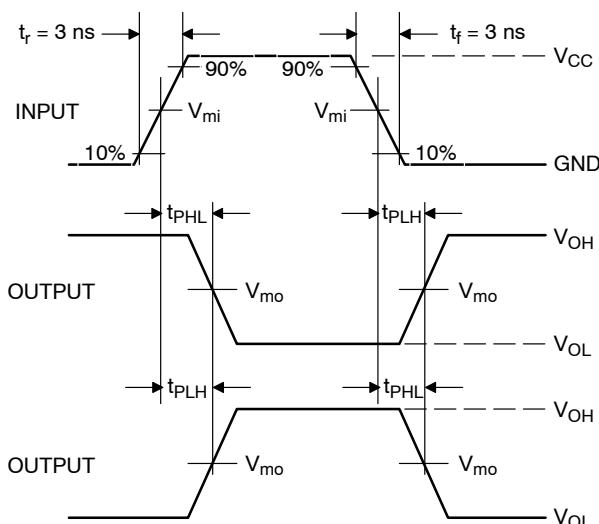


Figure 4. Switching Waveforms

V_{CC} , V	V_{mi} , V	V_{mo} , V		V_Y , V
		t_{PLH}, t_{PHL}	$t_{PZL}, t_{PLZ}, t_{PZH}, t_{PHZ}$	
3.0 to 3.6	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	0.3
4.5 to 5.5	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	0.3

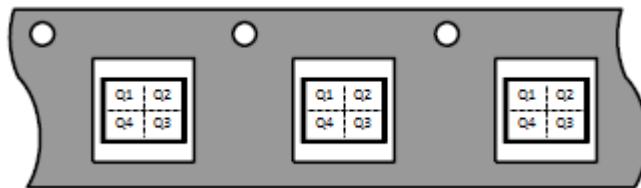
ORDERING INFORMATION

Device	Packages	Specific Device Code	Pin 1 Orientation (See below)	Shipping [†]
MC74VHC1G09DFT1G	SC-88A	VX	Q2	3000 / Tape & Reel
MC74VHC1G09DFT2G	SC-88A	VX	Q4	3000 / Tape & Reel
MC74VHC1G09DBVT1G	SC-74A	VX	Q4	3000 / Tape & Reel

[†] For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

Pin 1 Orientation in Tape and Reel

Direction of Feed



REVISION HISTORY

Revision	Description of Changes	Date
19	Removed five package ordering options and OPNs	1/14/2026

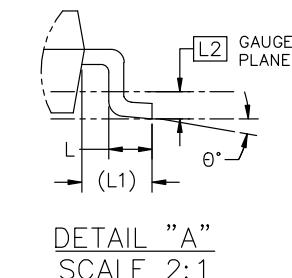
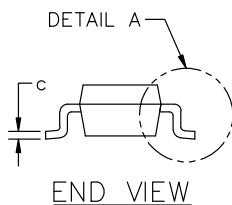
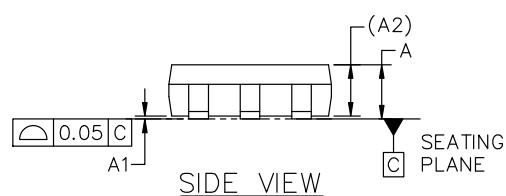
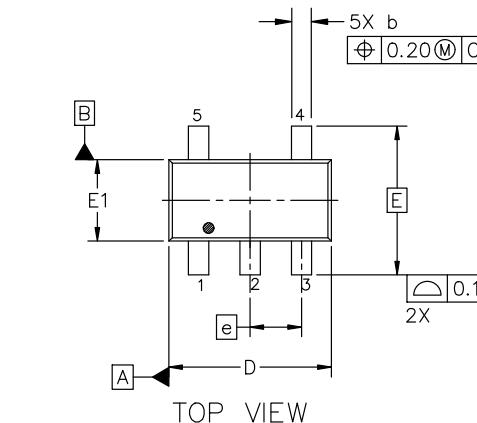
* Please note that this document has been previously updated prior to the inclusion of this revision history table and that the changes tracked only reflect what has occurred on the noted approval dates.



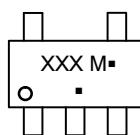


SC-74A-5 3.00x1.50x0.95, 0.95P
CASE 318BQ
ISSUE C

DATE 26 FEB 2024



**GENERIC
MARKING DIAGRAM***



XXX = Specific Device Code
M = Date Code
- = Pb-Free Package

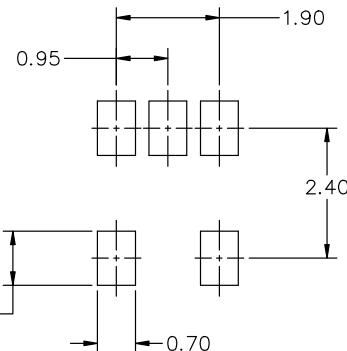
(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

NOTES:

1. DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
2. ALL DIMENSION ARE IN MILLIMETERS (ANGLES IN DEGREES).
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OF GATE BURRS, MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE.

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.90	1.00	1.10
A1	0.01	0.18	0.10
A2 0.95 REF.			
b	0.25	0.37	0.50
c	0.10	0.18	0.26
D	2.85	3.00	3.15
E	2.75 BSC		
E1	1.35	1.50	1.65
e	0.95 BSC		
L	0.20	0.40	0.60
L1	0.62 REF.		
L2	0.25 BSC		
θ	0°	5°	10°

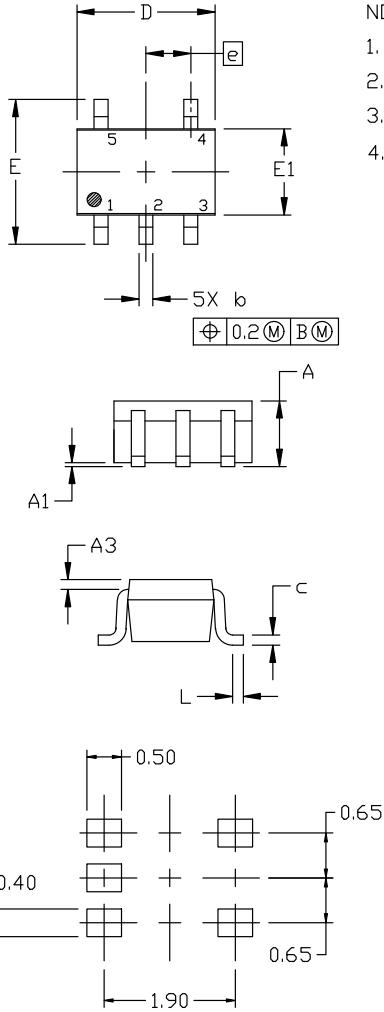


RECOMMENDED MOUNTING FOOTPRINT*

* FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

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DESCRIPTION:	SC-74A-5 3.00x1.50x0.95, 0.95P	PAGE 1 OF 1

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SCALE 2:1
RECOMMENDED
MOUNTING FOOTPRINT

* For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLE 1:
PIN 1. BASE
2. Emitter
3. BASE
4. COLLECTOR
5. COLLECTOR

STYLE 6:
PIN 1. Emitter 2
2. BASE 2
3. Emitter 1
4. COLLECTOR
5. COLLECTOR 2/BASE 1

STYLE 2:
PIN 1. ANODE
2. Emitter
3. BASE
4. COLLECTOR
5. CATHODE

STYLE 7:
PIN 1. BASE
2. Emitter
3. BASE
4. COLLECTOR
5. COLLECTOR

STYLE 3:
PIN 1. ANODE 1
2. N/C
3. ANODE 2
4. CATHODE 2
5. CATHODE 1

STYLE 8:
PIN 1. CATHODE
2. COLLECTOR
3. N/C
4. BASE
5. Emitter

STYLE 4:
PIN 1. SOURCE 1
2. DRAIN 1/2
3. SOURCE 1
4. GATE 1
5. GATE 2

STYLE 9:
PIN 1. ANODE
2. CATHODE
3. ANODE
4. ANODE
5. ANODE

STYLE 5:
PIN 1. CATHODE
2. COMMON ANODE
3. CATHODE 2
4. CATHODE 3
5. CATHODE 4

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

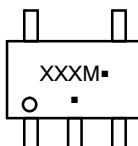
SC-88A (SC-70-5/SOT-353)
CASE 419A-02
ISSUE M

DATE 11 APR 2023

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS
3. 419A-01 OBSOLETE. NEW STANDARD 419A-02
4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.80	0.95	1.10
A1	---	---	0.10
A3 0.20 REF			
b	0.10	0.20	0.30
c	0.10	---	0.25
D	1.80	2.00	2.20
E	2.00	2.10	2.20
E1	1.15	1.25	1.35
e	0.65 BSC		
L	0.10	0.15	0.30

GENERIC MARKING
DIAGRAM*

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code
M = Date Code
■ = Pb-Free Package

(Note: Microdot may be in either location)

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